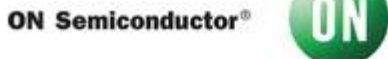









|   |   |
|---|---|
|  | <h2 style="color: red;">FQP7N10L</h2>   |
|  | <b>Hersteller-Teilenummer:</b> FQP7N10L   |
|   | <b>Hersteller / Marke:</b> AMI Semiconductor / ON Semiconductor   |
|   | <b>Teil der Beschreibung:</b> MOSFET N-CH 100V 7.3A TO-220  |
|   | <b>Datenblätter:</b> <ul style="list-style-type: none"> <li> <a href="#">1.FQP7N10L.pdf</a></li> <li> <a href="#">2.FQP7N10L.pdf</a></li> </ul> |
|   | <b>RoHs Status:</b> Bleifrei / RoHS-konform   |
|   | <b>Lagerzustand:</b> New original, 64773 pcs Stock Available.   |
|   | <b>Liefern von:</b> Hong Kong   |
|   | <b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS  |
| <p>Image may be representation.<br/>See specs for product details.</p>            |   |

### Spezifikationen

|  |   |
|--|---|
| Teilenummer                                      | FQP7N10L  |
| Hersteller                                       | AMI Semiconductor / ON Semiconductor                                |
| Beschreibung                                     | MOSFET N-CH 100V 7.3A TO-220  |
| Kategorie  | <a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a> |
| Teilstatus                                       | 64773 pcs Stock   |
| detaillierte Beschreibung                        | N-Channel 100V 7.3A (Tc) 40W (Tc) Through Hole TO-                  |
| Serie  | QFET®   |
| Technologie                                      | MOSFET (Metal Oxide)  |
| Betriebstemperatur                               | -55°C ~ 175°C (TJ)  |
| Befestigungsart                                  | Through Hole  |
| Verpackung / Gehäuse                             | TO-220-3  |
| Supplier Device-Gehäuse                          | TO-220-3  |
| Verlustleistung (max)                            | 40W (Tc)  |
| Typ FET  | N-Channel   |
| FET-Merkmal                                      | -   |
| Drain-Source-Spannung (Vdss)                     | 100V  |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 7.3A (Tc)   |
| Rds On (Max) @ Id, Vgs                           | 350 mOhm @ 3.65A, 10V   |
| VGS (th) (Max) @ Id                              | 2V @ 250µA  |
| Gate Charge (Qg) (Max) @ Vgs                     | 6nC @ 5V  |
| Eingabekapazität (Ciss) (Max) @ Vds              | 290pF @ 25V   |
| Antriebsspannung (Max Rds On, Min Rds On)        | 5V, 10V   |
| Vgs (Max)  | ±20V  |
| Verpackung                                       | Tube  |
| Bleifreier Status / RoHS-Status                  | Lead free / RoHS Compliant  |
| Feuchtigkeitsempfindlichkeitsniveau (MSL)        | 1 (Unlimited)   |



















































FQP7N10L ist neu im Original, Suche FQP7N10L Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP7N10L AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQP7N10L: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

|   |  |   |   |
|---|--|---|---|
| <br><b>FQP7N10</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 100V 7.3A TO-220           | <br><b>FQP7N20L</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 200V 6.5A TO-220 | <br><b>FQP7N20L</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 200V 6.5A TO-220 | <br><b>FQP7N20</b><br>Fairchild/ON Semiconductor<br>MOSFET N-CH 200V 6.6A TO-220           |
| <br><b>FQP70N10</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 100V 57A TO-220 | <br><b>FQP70N15</b><br>FAIRCHI<br>FQP70N15 FAIRCHI                                | <br><b>FQP7N10</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 100V 7.3A TO-220  | <br><b>FQP7N20</b><br>AMI Semiconductor / ON Semiconductor<br>MOSFET N-CH 200V 6.6A TO-220 |

heiße Teile

Mehr

|  |  |  |   |   |
|--|--|--|---|---|
|  FQP5N60C   |  FQP5N60C   |  FQP630TSTU |  FQP630TSTU |  FQP65N06  |
|  FQP65N06   |  FQP6N40C   |  FQP6N40C   |  FQP6N40CF  |  FQP6N40CF |
|  FQP6N50C   |  FQP6N50C   |  FQP6N60C   |  FQP6N60C   |  FQP6N80C  |
|  FQP6N80C   |  FQP6N90C   |  FQP6N90C   |  FQP70N03L  |  FQP70N06  |
|  FQP70N06C  |  FQP70N08   |  FQP70N08   |  FQP70N10   |  FQP70N10  |
|  FQP7N10L   |  FQP7N20L   |  FQP7N20L   |  FQP7N60C   |  FQP7N65C  |
|  FQP7N65C   |  FQP7N80C   |  FQP7N80C   |  FQP85N06   |  FQP85N06  |
|  FQP8N50C   |  FQP8N60C   |  FQP8N60C   |  FQP8N65C   |  FQP8N80C  |
|  FQP8N80C   |  FQP8N90C   |  FQP8N90C   |  FQP90N08   |  FQP90N08  |
|  FQP90N10V2 |  FQP90N10V2 |  FQP9N08L   |  FQP9N08L   |  FQP9N25C  |

Contact us:[Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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